Home » ROHM » ROHM BD7280YG-C Voltage Follower Low Noise and Input-Output Rail-to-Rail High Speed CMOS Operational Amplifier for Automotive User Guide [™]

ROHM BD7280YG-C Voltage Follower Low Noise and Input-Output Rail-to-Rail High Speed CMOS Operational Amplifier for Automotive User Guide

ROHM BD7280YG-C Voltage Follower Low Noise and Input-Output Rail-to-Rail High Speed CMOS

Operational Amplifier for Automotive User Guide



This circuit simulates the frequency response with Op-Amp as a voltage follower. You can observe the AC gain and phase of the ratio of output to input voltage when the input source voltage AC frequency is changed. You can customize the parameters of the components shown in blue, such as VSOURCE, or peripheral components, and simulate the voltage follower with the desired operating condition. You can simulate the circuit in the published application note: Operational amplifier, Comparator (Tutorial). [JP] [EN] [CN] [KR]

Contents

- **1 General Cautions**
- 2 Simulation Schematic
- 3 How to simulate
- **4 Simulation Conditions**
- 5 Op-Amp model
- **6 Peripheral Components**
- 7 Recommended

Products

- 8 Documents / Resources
 - 8.1 References

General Cautions

Caution 1: The values from the simulation results are not guaranteed. Please use these results as a guide for your design.

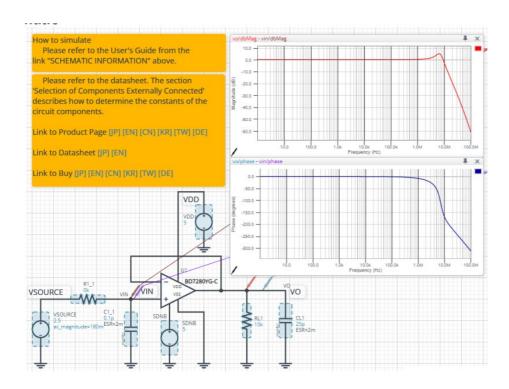
Caution 2: These model characteristics are specifically at Ta=25°C. Thus, the simulation result with temperature variances may significantly differ from the result with the one done at actual application board (actual

measurement).

Caution 3: Please refer to the Application note of Op-Amps for details of the technical information.

Caution 4: The characteristics may change depending on the actual board design and ROHM strongly recommend to double check those characteristics with actual board where the chips will be mounted on.

Simulation Schematic



How to simulate

The simulation settings, such as parameter sweep or convergence options, are configurable from the 'Simulation Settings' shown in Figure 2, and Table 1 shows the default setup of the simulation. In case of simulation convergence issue, you can change advanced options to solve. The temperature is set to 27 °C in the default statement in 'Manual Options'. You can modify it.

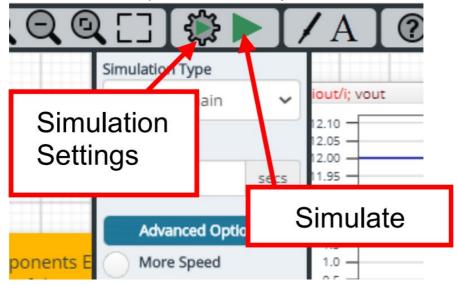


Figure 2. Simulation Settings and execution

Table 1. Simulation settings default setup

Parameters	Default	Note
Simulation Type	Frequency-Domain	Do not change Simulation Type
Start Frequency	0 Hz	Simulate the frequency response for the frequen
End Frequency	100Meg Hz	cy range from 0 Hz to 100 MHz.
	Balanced	-
Advanced options	Time Resolution EnhancementConvergence Assist	_
Manual Options	.temp 27	_

Simulation Conditions

Table 2. List of the simulation condition parameters

Instance Na me	Type	Parameters	Default Value	Variable Range		Units
	Туре			Min	Max	Uillis
VSOURCE	Voltage Source	Voltage_level	2.5	0	5.5	V
		AC_magnitude	180m	free		V
		AC_phase	0.0	fixed		0
VDD	Voltage Source fo r Op-Amp	Voltage_level	5	0(Note1)	5.5(Note 1)	V
		AC_magnitude	0.0	fixed		V
		AC_phase	0.0	fixed		0
SDNB	Voltage SourceFor Shutd own Setting	Voltage_level	5	VSS	VDD	V
		AC_magnitude	0.0	fixed		V
		AC_phase	0.0	fixed		0

(Note 1) Set it to the guaranteed operating range of the Op-Amps.

Op-Amp model

Table 3 shows the model pin function implemented. Note that the Op-Amp model is the behavioral model for its input/output characteristics, and neither protection circuits nor functions unrelated to the purpose are implemented.

Table 3. Op-Amp model pins used for the simulation

Pin Name	Description		
+IN	Non-inverting input		
-IN	Inverting input		
VDD	Positive power supply		
VSS	Negative power supply / Ground		
OUT	Output		
SDNB	Shutdown setting		

Peripheral Components

Bill of Material

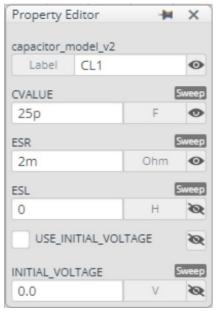
Table 4 shows the list of components used in the simulation schematic. Each of the capacitors has the parameters of equivalent circuit shown below. The default values of equivalent components are set to zero except for the ESR of C. You can modify the values of each component.

Table 4. List of capacitors used in the simulation circuit

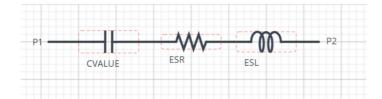
Туре	Instance Name	Default Value	Variable Range		Units
			Min	Max	Oilles
Resistor	R1_1	0	0	10	kΩ
	RL1	10k	1k	1M, NC	Ω
Capacitor	C1_1	0.1	0.1	22	pF
	CL1	25	free, NC		pF

Capacitor Equivalent Circuits

(a) Property editor



(b) Equivalent circuit



The default value of ESR is $2m \Omega$.

(Note 2) These parameters can take any positive value or zero in simulation but it does not guarantee the operation of the IC in any condition. Refer to the datasheet to determine adequate value of parameters.

Recommended Products

Op-Amp

BD7280YG-C: Nano Cap™, Low Noise & Input/Output Rail-to-Rail High Speed CMOS Operational Amplifier for Automotive. [JP] [EN] [CN] [KR] [TW] [DE] Technical Articles and Tools can be found in the Design Resources on the product web page.

Documents / Resources



ROHM BD7280YG-C Voltage Follower Low Noise and Input-Output Rail-to-Rail High Spee d CMOS Operational Amplifier for Automotive [pdf] User Guide

BD7280YG-C Voltage Follower Low Noise and Input-Output Rail-to-Rail High Speed CMOS Op erational Amplifier for Automotive, BD7280YG-C, Voltage Follower Low Noise and Input-Output Rail-to-Rail High Speed CMOS Operational Amplifier for Automotive

References

- RBD7280YG-C ROHM Semiconductor
- RBD7280YG-C ROHM.co.kr
- R BD7280YG-C ROHM.com.cn
- BD7280YG-C ROHM.com.tw
- R BD7280YG-C Data Sheet, Product Detail | ROHM.com
- R BD7280YG-C Data Sheet, Produktdetails | ROHM.de

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